

	<h2 style="color: red;">NTD5406NG</h2>
	<p>Hersteller-Teilenummer: NTD5406NG</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 40V 70A DPAK</p> <hr/> <p>Datenblätter:  NTD5406NG.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 42423 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD5406NG
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 40V 70A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	42423 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	3W (Ta), 100W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	12.2A (Ta), 70A (Tc)
Rds On (Max) @ Id, Vgs	10 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	3.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	45nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2500pF @ 32V
Verpackung	Tube




























































NTD5406NG ist neu im Original. Suche NTD5406NG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD5406NG AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD5406NG: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD5406T4G O NTD5406T4G O</p>	 <p>NTD5407NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 38A DPAK</p>	 <p>NTD517VS-TL-E SANYO SANYO SOT23-8</p>	 <p>NTD5406N ON NTD5406N ON</p>
 <p>NTD5407N ON NTD5407N ON</p>	 <p>NTD5406NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 70A DPAK</p>	 <p>NTD50N06 VB NTD50N06 VB</p>	 <p>NTD50N03T4G O NTD50N03T4G O</p>

heiße Teile

Mehr

 NTD4963N-1G	 NTD4963N-35G	 NTD4963NT4G	 NTD4965N	 NTD4965N-35G
 NTD4965NT4G	 NTD4969N	 NTD4969N-1	 NTD4969N-1G	 NTD4969NT4G
 NTD4970N	 NTD4970N-1	 NTD4970N-1G	 NTD4970N-35G	 NTD4970NT4G
 D NTD50N03R-001	 NTD50N03R-035	 NTD50N03R-1G	 NTD50N03R-35G	 NTD50N03RG
  NTD50N03RT4	  NTD50N03RT4G	 NTD50N03T4G	 NTD50N06	 NTD5406N
  NTD5406NT4G	  NTD5406T4G	 D NTD5407N	 NTD5407NG	 NTD5407NT4G
 NTD5412NT4G	 D NTD5413N	  NTD5413NT4G	  NTD5414N	 NTD5414NT4G
 NTD5426NT4G	 NTD5802N	  NTD5802NT4G	  NTD5803N	 NTD5803NT4G
 NTD5804N	 NTD5804NG	 NTD5804NT4G	 D NTD5805N	 NTD5805NG
  NTD5805NT4G	 NTD5806N	 NTD5806NG	 NTD5806NT4G	 NTD5807N

Contact us: Info@Y-IC.com

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